

Model RFP-250375N4Z50-2

RF Power

Aluminum Nitride Terminations 25 Watts, 50 Ω



Features

- DC 3.0 GHz
- 25 Watts
- Aluminum Nitride (AIN) Ceramic
- Surface Mountable
- Non-Nichrome Resistive Element
- Low VSWR
- 100% Tested

General Specifications

Resistive Element: Thick film

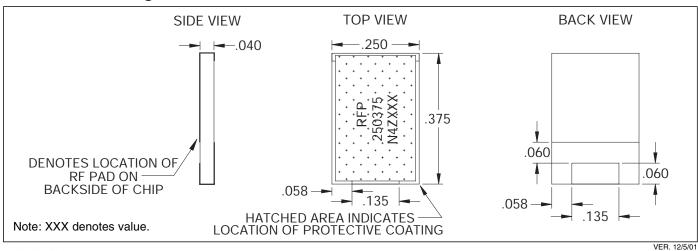
Substrate: Aluminum nitride ceramic
Terminals: Tin/Lead, 90/10 over nickel

Electrical Specifications

Resistance Value: 50 ohms, ±2% Frequency Range: DC - 3.0 GHz Power: 25 Watts V.S.W.R.: 1.25:1

Notes: Tolerance is $\pm .010$, unless otherwise specified. Operating temperature is -55° C to $+125^{\circ}$ C (see chart). Designed to meet or exceed applicable portions of MIL-E-5400. All dimensions are in inches. **Specifications subject to change without notice.**

Outline Drawing



Available on Tape and Reel for Pick and Place Manufacturing.

Sales Desk USA: Voice: (800) 544-2414 Fax: (315) 432-9121 Sales Desk Europe: Voice: (+44) 23 92 232392 Fax: (+44) 23 92 251369

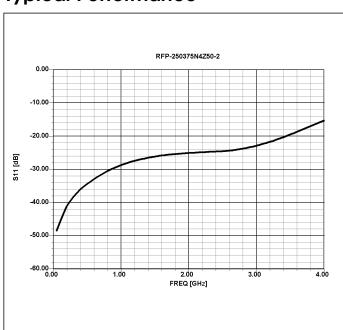


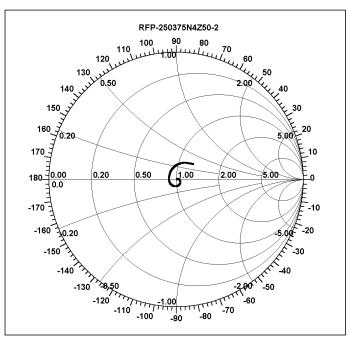
Model RFP-250375N4Z50-2



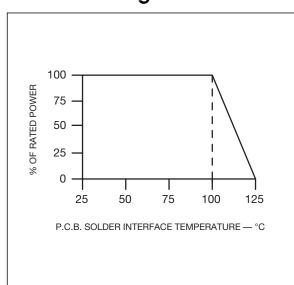


Typical Performance

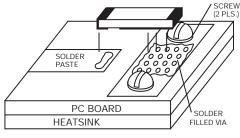




Power Derating



Suggested Mounting Procedures



- 1. Solder part in place using 60/40 type solder with controlled temperature iron (700°F).
- 2. Drill thermal vias through PCB and fill with solder, such as 60/40 type.
- To ensure good thermal connectivity to heat sink, drill and tap heatsink and mount PCB board to heat sink using screws.

Available on Tape and Reel for Pick and Place Manufacturing.





Sales Desk USA: Voice: (800) 544-2414 Fax: (315) 432-9121